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Inclosure Material:

Metal all transistor

Overall Length:

0.915 inches all transistor

Overall Diameter:

1.230 inches all transistor and 1.300 inches all transistor

Mounting Facility Quantity:

1 all transistor

Internal Configuration:

Junction contact all transistor

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-81 all transistor

Internal Junction Configuration:

Npn all transistor

Component Function Relationship:

Matched

Component Name And Quantity:

2 transistor

Mounting Method:

Threaded stud all transistor

Features Provided:

Hermetically sealed case

Thread Size:

0.312 inches all transistor

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

100.0 breakdown voltage, collector-to-emitter, base open all transistor

Current Rating Per Characteristic:

10.00 amperes source cutoff current all transistor and 20.00 milliamperes zero-gate-voltage source current preset all transistor

Power Rating Per Characteristic:

150.0 watts small-signal input power, common-collector absolute all transistor

Thread Series Designator:

Unf all transistor

Terminal Type And Quantity:

2 pin all transistor and 1 threaded stud all transistor

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fig:

A110a0